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Substitute for form 1449/PTO Application Number 10/750,073 12/31/2003 Filing Date INFORMATION DISCLOSURE First Named Inventor Shen-Kan Hsiung STATEMENT BY APPLICANT Art Unit 2814 Shrinivas H. Rao (Use as many sheets as necessary) Examiner Name 003-03-033 Attorney Docket Number Sheet ·

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Substitut	e for form 1449/PT(,		Application Number	10/750,073		
INFO	ORMATIO	N DIS	CLOSURE	Filing Date	12/31/2003		
STA	STATEMENT BY APPLICANT			First Named Inventor	Shen-Kan Hsiung		
				Art Unit	2814		
(Use as many sheets as necessary)				Examiner Name	Shrinivas H. Rao		
Sheet	2	of	3	Attorney Docket Number	003-03-033		

Examiner Cite No.1		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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Substitut	e for form 1448/PTO			Application Number	10/750,073			
INFO	DRMATIO	N DIS	CLOSURE	Filing Date	12/31/2003			
STA	TEMENT	BY A	PPLICANT	First Named Inventor	Shen-Kan Hsiung			
			i	Art Unit	2814			
	(Use as many si	199CS 85 A	ecossary)	Examiner Name	Shrinivas H. Rao			
Sheet	3	of	3	Attorney Docket Number	003-03-033			

		NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²				
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